Chemical state analysis of Silicon negative electrode material using SEM-SXES

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Introduction

Silicon (Si) has a large theoretical capacitance of 4200 mAh/g, and is attracting attention as a negative electrode material for Lithium (Li) ion secondary battery (LIB) to replace graphite. However, Si has problems such as volume expansion and decrease in charging efficiency during charging and discharging. Therefore, analysis for Si structure is being proceeded (1). However, the analysis of Li intercalation and desorption into Si is often evaluated based on electrochemical properties, and the detailed process of Li intercalation and desorption on the micron scale has not been clarified. Therefore, there is a need for micron-scale structural analysis of Si in the charge-discharge process based on chemical state analysis. The purpose of this study is to perform elemental analysis using Energy dispersive spectrometry (EDS), chemical state analysis using Soft X-ray emission spectrometry (SXES), and crystal structure analysis using Electron backscattered diffraction (EBSD), with a Field Emission-Scanning electron microscope (FE-SEM) for the Si negative electrode of LIB, and attempting structural analysis of Si particles in charging state.

Materials and Preparation

Sample

90% Charged Si negative electrode

particles were used for negative

electrode. A half-cell was prepared

using this negative electrode and

charged at 90% of the theoretical

capacitance value of Si.

(half cell)

Reference electrode (In-Li alloy)

Si negative electrode layer



LPSI solid electrolyte prepared by liquid-phase syntheses ⁽²⁾ and Si



Instruments for chemical state analysis





Low energy X-rays can be measured by SXES. This is important as these Xrays give information about the valence band.



It is possible to obtain valence band information with high energy resolution. The chemical state (differences of compound and crystal) is reflected in the spectral shape.

The shape of Si L emission spectrum of (a) coincides with that of the spectrum of crystalline Si as a reference. The EBSD pattern of (a) is also indexed with the EBSD pattern expected for crystalline Si. Therefore, uncharged crystalline Si remains in this part. On the other hand, the shapes of Si L and Li K emission spectra obtained at (b) suggest that Si and Li are alloyed. The EBSD pattern of (b) is indexed with the EBSD pattern expected for crystalline structure of Li₁₅Si₄ which is formed by charging. From these results, it can be confirmed that the alloys of Si and Li are mixed in several states inside the Si particle during the charging process.

Summary

In the analysis of the negative electrode Si, the Li content and the chemical state such as crystallinity can be detected at once using SEM-SXES. The distribution of Si and Li in the negative electrode layer correlates with the BSE image and EDS elemental maps. In the BSE image, the bright part had a low Li concentration and the dark part had a high Li concentration. This suggests that the Li concentration is high near the solid electrolyte layer and the Li concentration decreases toward the surface of the negative electrode layer. In the analysis inside the Si particle, the Li content, crystallinity, and alloying state were determined by SEM-SXES, the alloy type was determined by EBSD, and these two phases could be identified as Li₁₅Si₄ and crystalline Si. The combination of the SEM-SXES method, EDS analysis, and EBSD analysis provided information on the crystal structure and chemical state, and the structural analysis inside a single particle of Si could be performed on a micron-scale. These results demonstrate the effectiveness of this method for Si negative electrode analysis in LIB.

References (1) Obrovac.M.N et al., Electrochem. and Solid-State Lett., Vol.7, Num. 5, (2004), A93 (3) Terauchi. M et al., Journal of Electron Microscopy, Vol. 61, (2012), P. 1–8



